# **Power MOSFET**

# 8 V, 4.3 A, High Side Load Switch with Level Shift, 2x2 mm WDFN Package

#### **Features**

- WDFN 2x2 mm Package with Exposed Drain Pads Offers Excellent Thermal Performance
- Low R<sub>DS(on)</sub> P-Channel Load Switch with N-channel MOSFET for Level Shift
- N Channel Operated at 1.5 V Gate Drive Voltage Level
- P Channel Operated at 1.5 V Supply Voltage
- Same Footprint as SC88
- Low Profile (<0.8 mm) Allows it to Fit Easily into Extremely Thin **Environments**
- ESD Protection
- These are Pb-Free Devices

#### **Applications**

- High Slide Load Switch with Level Shift
- Optimized for Power Management in Ultra Portable Equipment

## **MOSFET(Q2) MAXIMUM RATINGS**

 $(T_J = 25^{\circ}C \text{ unless otherwise stated})$ 

Parameter			Symbol	Value	Unit
Q2 Input Voltage (V <sub>DS</sub> , P-Channel)			V <sub>IN</sub>	8	٧
Q1 On/Off Voltage (V <sub>GS</sub> , N-Channel)			V <sub>ON/OFF</sub>	6	V
Continuous Load	Steady	T <sub>A</sub> = 25°C	Ι <sub>L</sub>	4.3	Α
Current (Note 1)	State	T <sub>A</sub> = 85°C		3.1	
Power Dissipation (Note 1)	Steady State	T <sub>A</sub> = 25°C	P <sub>D</sub>	1.56	W
Continuous Load Current (Note 2)	Steady	T <sub>A</sub> = 25°C	ΙL	2.5	Α
		T <sub>A</sub> = 85°C		1.8	
Power Dissipation (Note 2)	State	T <sub>A</sub> = 25°C	P <sub>D</sub>	0.52	W
Pulsed Load Current				20	Α
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C
Source Current (Body Diode) (Note 2)			I <sub>S</sub>	-2.7	Α
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

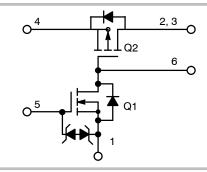
- Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces)
- 2. Surface-mounted on FR4 board using the minimum recommended pad size.



## ON Semiconductor®

## www.onsemi.com

V <sub>INMAX</sub>	R <sub>DS(on)</sub> MAX	I <sub>L</sub> MAX
20 V	50 mΩ @ 4.5 V	
	60 mΩ @ 2.5 V	4.3 A
	80 mΩ @ 1.8 V	4.5 A
	115 mΩ @ 1.5 V	





## **MARKING DIAGRAM**

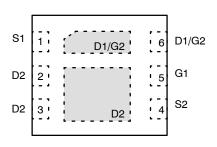
JN M= 5

= Specific Device Code

= Date Code

= Pb-Free Package (Note: Microdot may be in either location)

# **PIN CONNECTIONS**



(Top View)

### ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

## THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 3)	$R_{ heta JA}$	80	°C/W
Junction-to-Ambient - t ≤ 5 s (Note 3)	$R_{ heta JA}$	38	°C/W
Junction-to-Ambient - Steady State Min Pad (Note 4)	$R_{ heta JA}$	180	°C/W

Surface Mounted on FR4 Board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
 Surface-mounted on FR4 board using the minimum recommended pad size.

# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Q2 Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu A$		-8.0			V
Q2 Forward Leakage Current	I <sub>FL</sub>	V <sub>ON/OFF</sub> = 0 V, T <sub>J</sub> = 25°C				0.1	μΑ
		V <sub>IN</sub> = 8.0 V	T <sub>J</sub> = 85°C			1	
Q1 Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS1} = \pm 6 \text{ V}$				±100	nA
Q1 Diode Forward On-Voltage	$V_{SD}$	I <sub>S</sub> = -1.0 A, V <sub>GS1</sub> = 0 V			-0.8	-1.1	V
ON CHARACTERISTICS							
Q1 ON/OFF Voltage	V <sub>ON/OFF</sub>			1.5		8.0	
Q1 Gate Threshold Voltage	V <sub>GS1(TH)</sub>	$V_{GS1} = V_{DS1}, I_D = 250 \mu A$		0.40		1.0	V
Q2 Input Voltage	V <sub>IN</sub>			1.8		8.0	V
Q2 Drain-to-Source On	R <sub>DS(on)</sub>	$V_{IN} = 4.5 \text{ V, } I_L = 4.0 \text{ A}$ $V_{IN} = 2.5 \text{ V, } I_L = 3.0 \text{ A}$ $V_{IN} = 1.8 \text{ V, } I_L = 1.7 \text{ A}$			33	50	mΩ
Resistance					40	60	1
					60	80	
		V <sub>IN</sub> = 1.5 V, I <sub>L</sub> :	= 1.2 A		75	115	1
Q2 Load Current	Ι <u>L</u>	$V_{DROP} \le 0.2 \text{ V}, V_{IN} = 2.5 \text{ V}, V_{ON/OFF} = 1.5 \text{ V}$		1.0			Α
	$V_{DROP} \le 0.3 \text{ V}, V_{IN} = 1.8 \text{ V}, V_{ON/OFF} = 1.5 \text{ V}$		V, V <sub>ON/OFF</sub> = 1.5 V	1.0			

# **TYPICAL PERFORMANCE CURVES** ( $T_J = 25^{\circ}C$ unless otherwise noted)

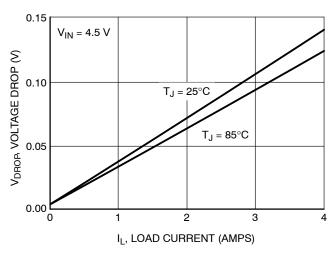


Figure 1. Voltage Drop versus Load Current @  $V_{IN} = 4.5 \text{ V}$ 

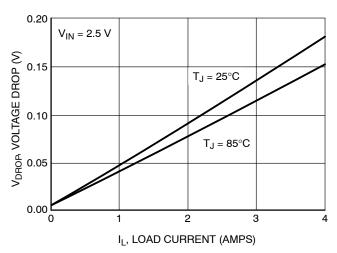


Figure 2. Voltage Drop versus Load Current @  $V_{\text{IN}}$  = 2.5 V

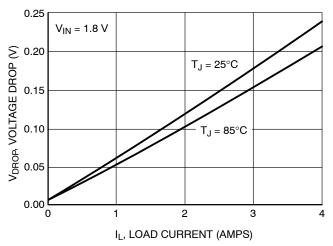


Figure 3. Voltage Drop versus Load Current @  $V_{\text{IN}} = 1.8 \text{ V}$ 

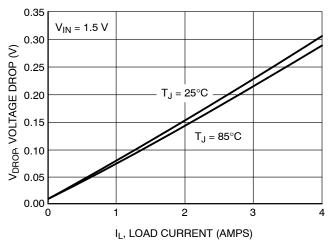
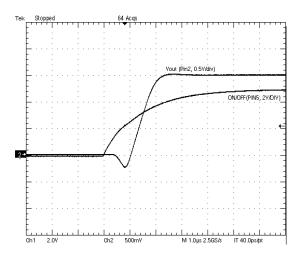


Figure 4. Voltage Drop versus Load Current @  $V_{IN} = 1.5 \text{ V}$ 

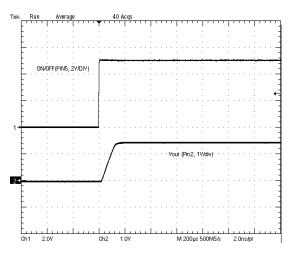
# TYPICAL PERFORMANCE CURVES (T $_{J}$ = 25°C unless otherwise noted)



Yout (Pin2, 0.5Y/div)

Figure 5. Turn-on  $(V_{in} = 1.5 \text{ V}, R_L = 3 \Omega, R1 = 1 \text{ k}\Omega, R2 = 0, C1 = 47 \text{ nF})$ 

Figure 6. Turn-off  $(V_{in} = 1.5 \text{ V}, R_L = 3 \Omega, R1 = 1 \text{ k}\Omega, R2 = 0, C1 = 47 \text{ nF})$ 



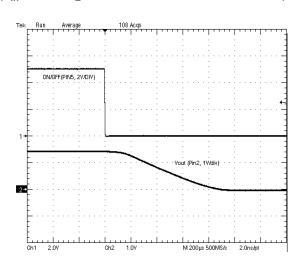
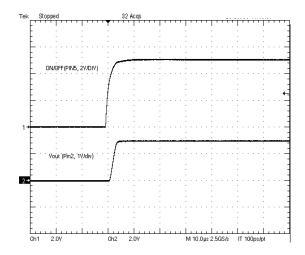


Figure 7. Turn-on

Figure 8. Turn-off  $(V_{in} = 1.5 \text{ V}, R_L = 3 \Omega, R1 = 10 \text{ k}\Omega, R2 = 1 \text{ k}\Omega, C1 = 47 \text{ nF})$   $(V_{in} = 1.5 \text{ V}, R_L = 3 \Omega, R1 = 10 \text{ k}\Omega, R2 = 1 \text{ k}\Omega, C1 = 47 \text{ nF})$ 



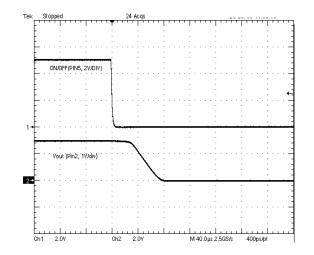


Figure 9. Turn-on  $(V_{in} = 3 \ V, \ R_L = 3 \ \Omega, \ R1 = 10 \ k\Omega, \ R2 = 1 \ k\Omega, \ C1 = 47 \ nF) \\ (V_{in} = 3 \ V, \ R_L = 3 \ \Omega, \ R1 = 10 \ k\Omega, \ R2 = 1 \ k\Omega, \ C1 = 47 \ nF)$ 

Figure 10. Turn-off

## TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = 25°C unless otherwise noted)

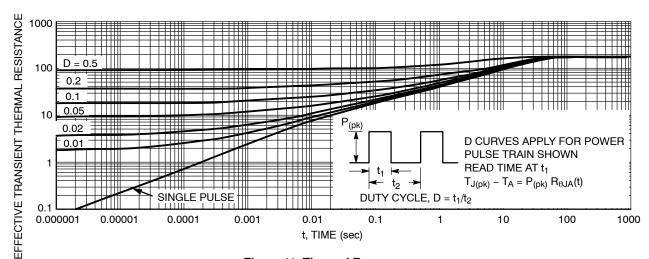


Figure 11. Thermal Response

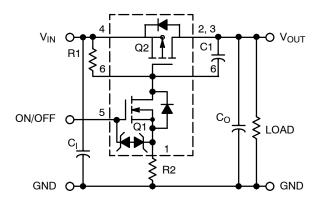


Figure 12. Load Switch Application

Components	Description	Value
R1	Pull-up Resistor	Typical 10 k $\Omega$ to 1.0 M $\Omega^*$
R2	Optional Slew-Rate Control	Typical 0 k $\Omega$ to 100 k $\Omega$ *
C <sub>O</sub> , C <sub>I</sub>	Output Capacitance	Usually < 1.0 μF
C1	Optional In-Rush Current Control	Typical ≤ 1000 pF

<sup>\*</sup>Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.

## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTLJD2105LTBG	WDFN6 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SCALE 4:1

PIN ONE REFERENCE

2X 🗀 0.10

0.10 C

6x |  $\bigcirc$  | 0.08 | C

6X L

NOTE 6

6X K

SOURCE 1 DRAIN 2

DRAIN 2 SOURCE 2

DRAIN 1

STYLE 1:

2.

5. GATE 1 D2

**BOTTOM VIEW** 

0.10 C



В

E

C SEATING

e 4X

2X E2

6X b

Ф 0.05 С NOTE 3

NOTE 5

0.10 C A

В

**DATE 25 APR 2006** 

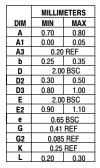
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20mm FROM
- I EHMINAL.

  4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

  1. PINS 2 & 3 CONNECTED TO LARGE FLAG.

  2. PIN 6 CONNECTED TO SMALL FLAG.



## **GENERIC MARKING DIAGRAM\***

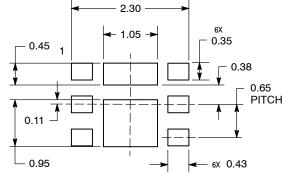


XX = Specific Device Code

= Date Code M

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

## SOLDERMASK DEFINED **MOUNTING FOOTPRINT**



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON22362D	Electronic versions are uncontrolled except when accessed directly from the Document Reposi Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	6 PIN WDFN 2X2, 0.65P		PAGE 1 OF 1

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.



onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

#### **PUBLICATION ORDERING INFORMATION**

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative